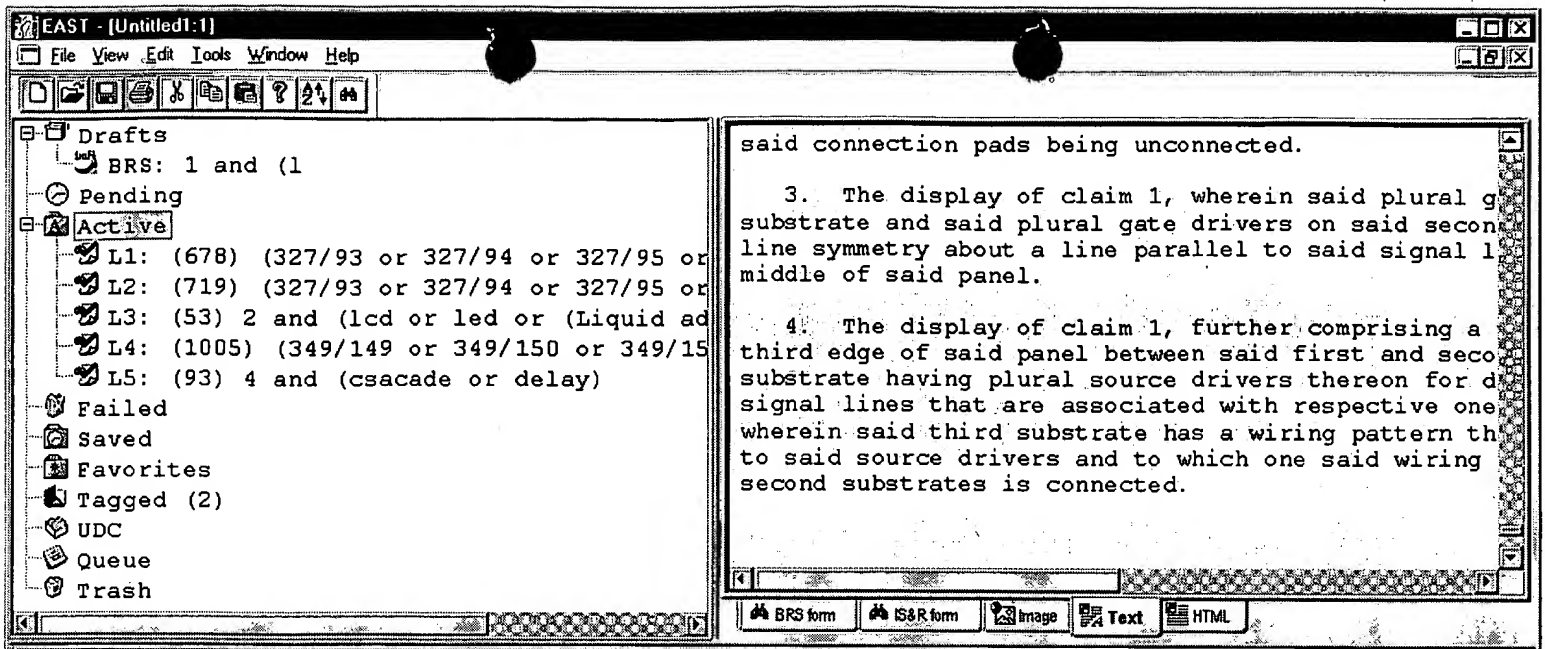

	Type	L #	Hits	Search Text	DBs
1	BRS	L1	678	(327/93 or 327/94 or 327/95 or 327/96).ccls.	USPAT
2	BRS	L2	719	(327/93 or 327/94 or 327/95 or 327/96).ccls.	USPAT; US-PGPUB
3	BRS	L3	53	2 and (lcd or led or (Liquid adj crystal))	USPAT; US-PGPUB
4	BRS	L4	1005	(349/149 or 349/150 or 349/151 or 349/152).ccls.	USPAT; US-PGPUB
5	BRS	L5	93	4 and (csacade or delay)	USPAT; US-PGPUB

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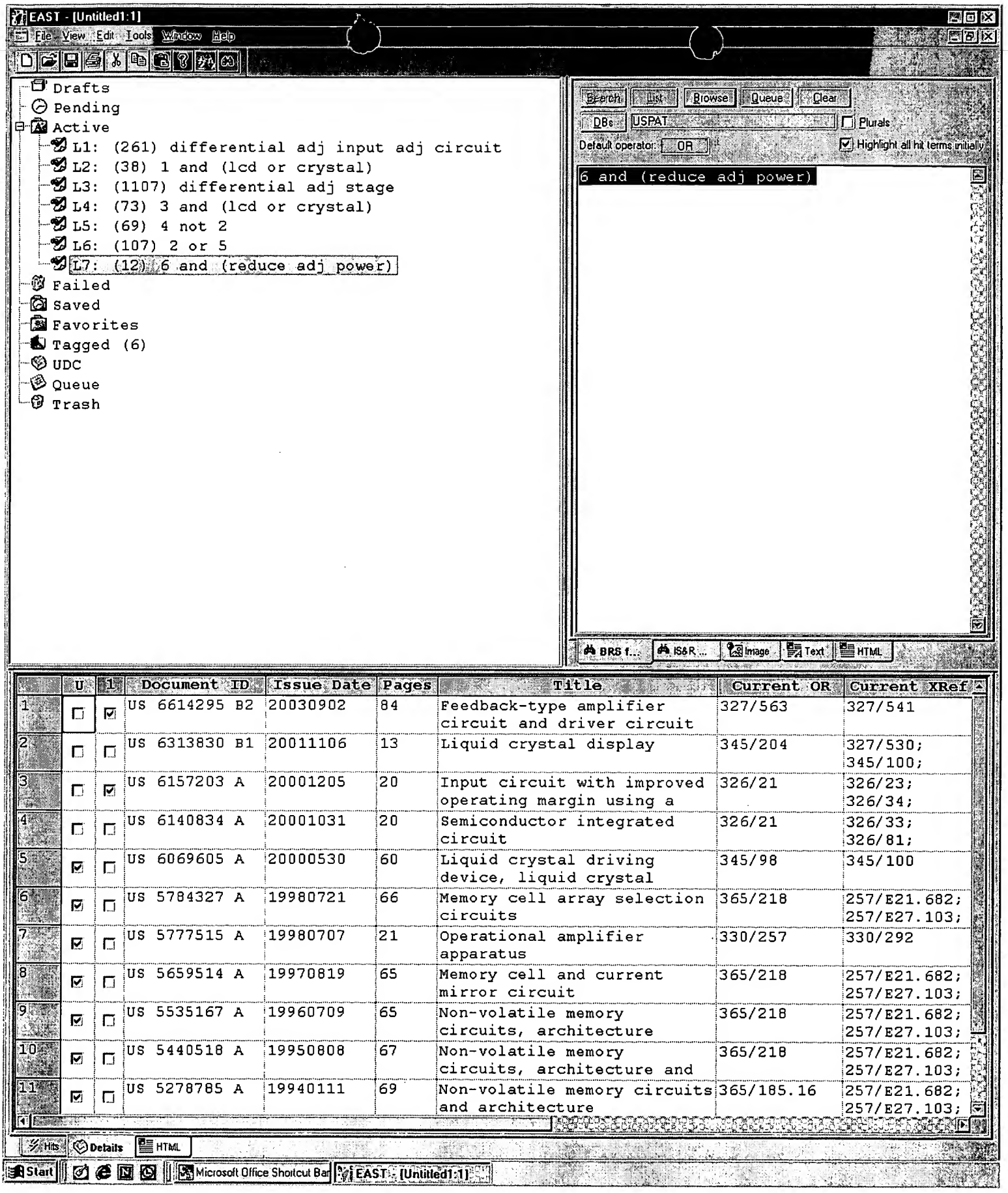

	U	1	Document ID	Issue Date	Pages	Title	Current OR	Current XRef
1	☐	☑	US 6614295 B2	20030902	84	Feedback-type amplifier circuit and driver circuit	327/563	327/541
2	☐	☐	US 6313830 B1	20011106	13	Liquid crystal display	345/204	327/530; 345/100;
3	☐	☑	US 6157203 A	20001205	20	Input circuit with improved operating margin using a	326/21	326/23; 326/34;
4	☐	☐	US 6140834 A	20001031	20	Semiconductor integrated circuit	326/21	326/33; 326/81;
5	☑	☐	US 6069605 A	20000530	60	Liquid crystal driving device, liquid crystal	345/98	345/100
6	☑	☐	US 5784327 A	19980721	66	Memory cell array selection circuits	365/218	257/E21.682; 257/E27.103;
7	☑	☐	US 5777515 A	19980707	21	Operational amplifier apparatus	330/257	330/292
8	☑	☐	US 5659514 A	19970819	65	Memory cell and current mirror circuit	365/218	257/E21.682; 257/E27.103;
9	☑	☐	US 5535167 A	19960709	65	Non-volatile memory circuits, architecture	365/218	257/E21.682; 257/E27.103;
10	☑	☐	US 5440518 A	19950808	67	Non-volatile memory circuits, architecture and	365/218	257/E21.682; 257/E27.103;
11	☑	☐	US 5278785 A	19940111	69	Non-volatile memory circuits and architecture	365/185.16	257/E21.682; 257/E27.103;

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